

این دیتاشیت توسط توکل الکترونیک تهیه و ارائه شده است.
جهت مشاهده قیمت، موجودی و ثبت سفارش این قطعه به وبسایت توکل الکترونیک مراجعه فرمایید.



مشاهده قیمت و خرید

برای خرید و مشاهده سایر محصولات کلیک کنید



6427525 N E C ELECTRONICS INC

98D 18918

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MOS FIELD EFFECT POWER TRANSISTORS 2SK739, 2SK739-Z

FAST SWITCHING
N-CHANNEL SILICON POWER MOS FET
INDUSTRIAL USE

FEATURES

- Suitable for switching power supplies, actuator controls, and pulse circuits.
- Low $R_{DS(on)}$
- No second breakdown
- 4 V Gate Drive – Logic level –
- Designed for Hybrid Integrated Circuits

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

Drain to Source Voltage	V_{DS}	60	V
Gate to Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	$I_{D(DC)}$	± 2.0	A
Peak Drain Current	$I_{D(pulse)}$ *	± 8.0	A
Total Power Dissipation	P_T **	20	W
Total Power Dissipation at 25°C Ambient Temperature	P_T ***	2.0	W
Channel Temperature	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to $+150$	$^\circ\text{C}$

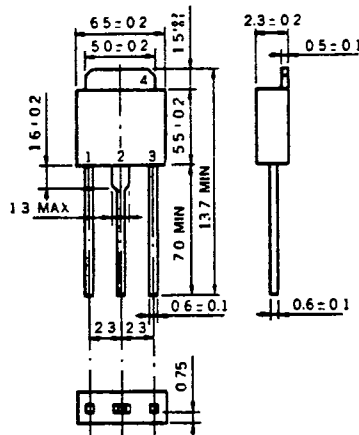
* $PW \leq 300 \mu\text{s}$, Duty Cycle $\leq 10\%$ ** $T_c = 25^\circ\text{C}$ *** Mounted on ceramic substrate of $2.5 \text{ cm}^2 \times 0.7 \text{ mm}$

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

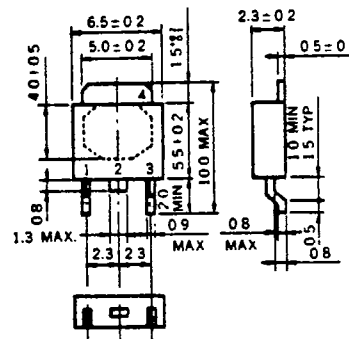
CHARACTERISTIC	SYMBOL	MIN.	TYP	MAX.	UNIT	TEST CONDITIONS
Drain Leakage Current	I_{DSS}			10	μA	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to Source Leakage Current	I_{GSS}			± 100	nA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Gate to Source Cutoff Voltage	$V_{GS(off)}$	1.0		2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Forward Transfer Admittance	$ Y_{fs} $	1.0			S	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)}$		0.17	0.25	Ω	$V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$
Drain to Source On-State Resistance	$R_{DS(on)}$		0.22	0.35	Ω	$V_{GS} = 4 \text{ V}, I_D = 0.8 \text{ A}$
Input Capacitance	C_{iss}		550		pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0$
Output Capacitance	C_{oss}		200		pF	$f = 1 \text{ MHz}$
Reverse Transfer Capacitance	C_{rss}		60		pF	
Turn-On Delay Time	$t_d(on)$		10		ns	$I_D = 1 \text{ A}, V_{CC} = 30 \text{ V}$
Rise Time	t_r		20		ns	$V_{GS(on)} = 10 \text{ V}$
Turn-Off Delay Time	$t_d(off)$		80		ns	$R_L = 30 \Omega$
Fall Time	t_f		20		ns	$R_{in} = 10 \Omega$

PACKAGE DIMENSIONS (Unit: mm)

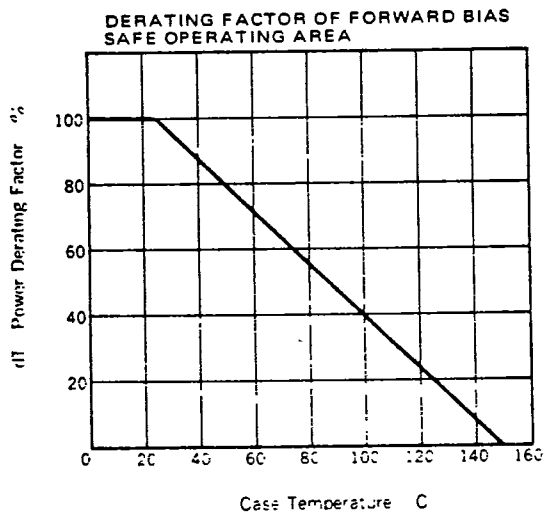
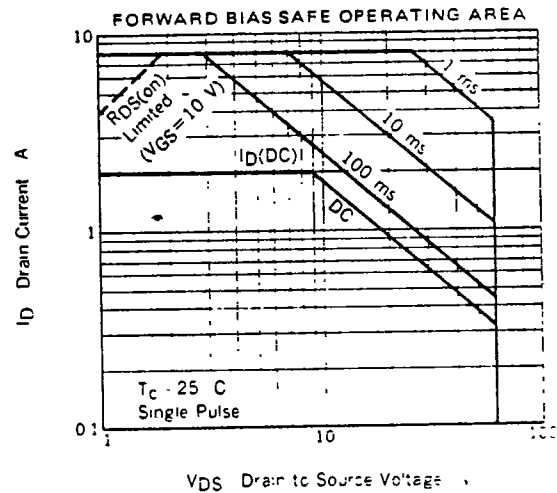
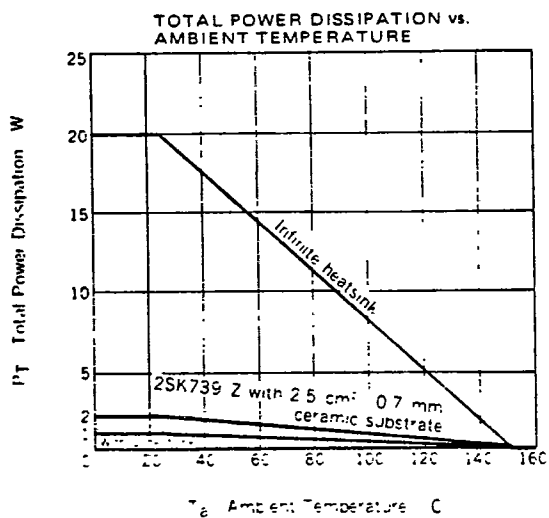
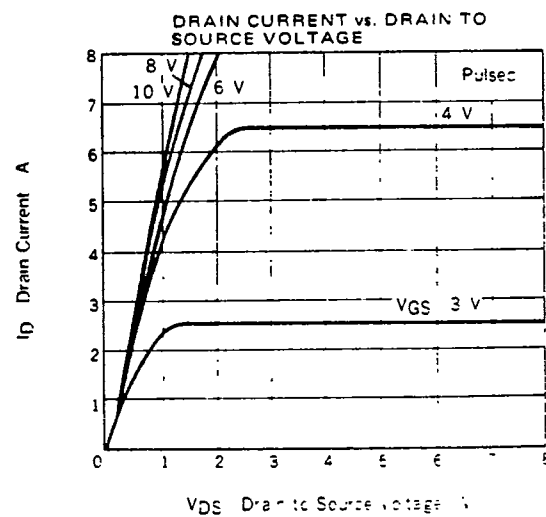
2SK739

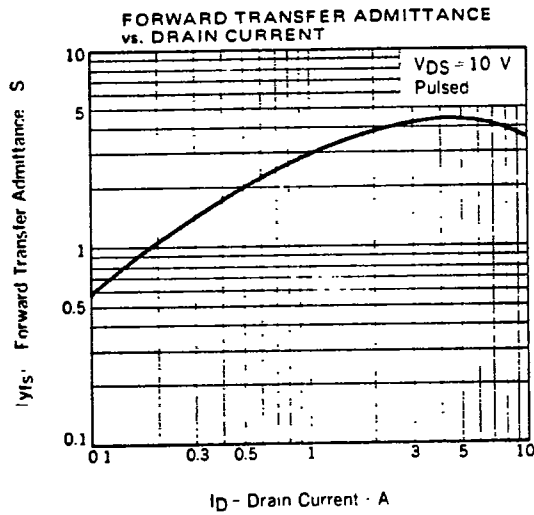
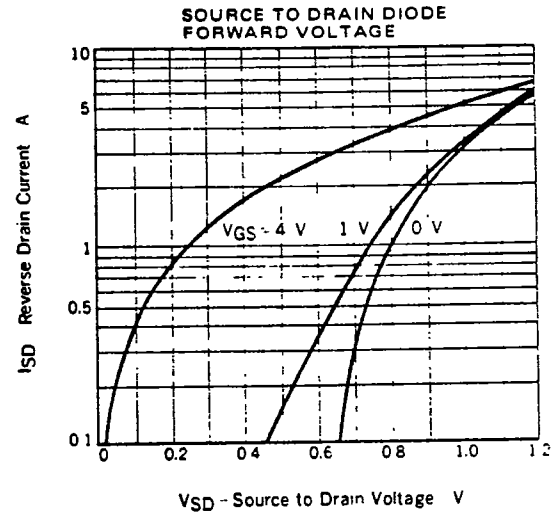
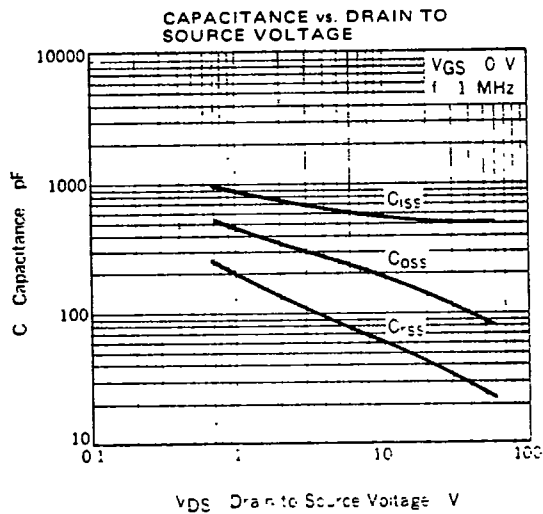
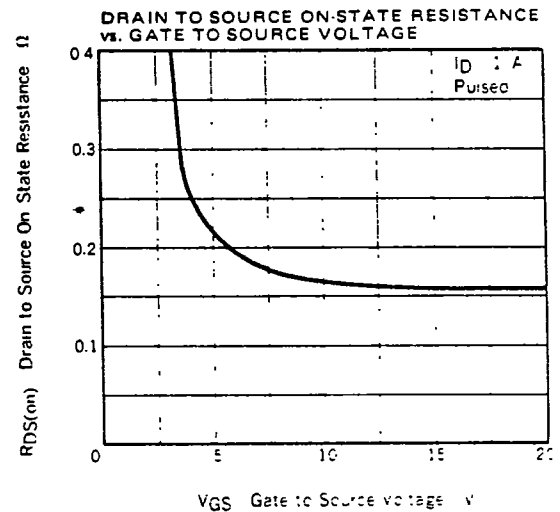
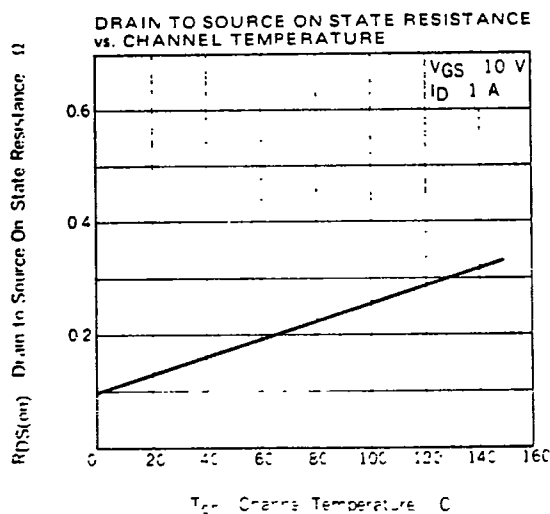
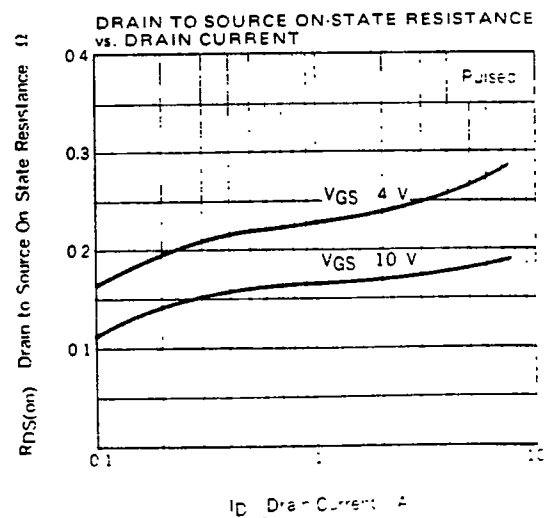


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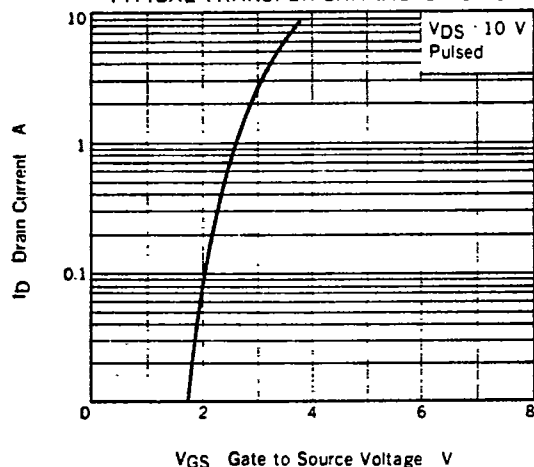


1. Gate
2. Drain
3. Source
4. Drain (Fin)

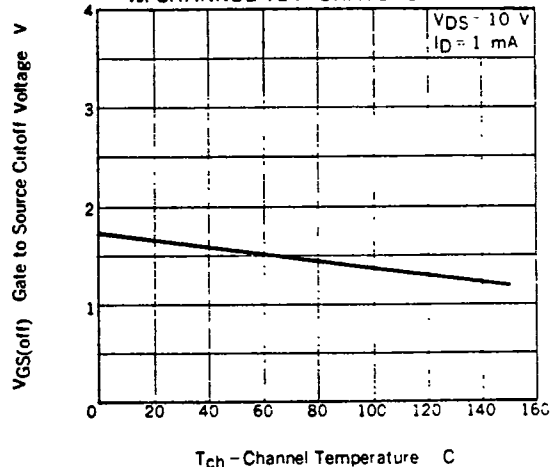
TYPICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)



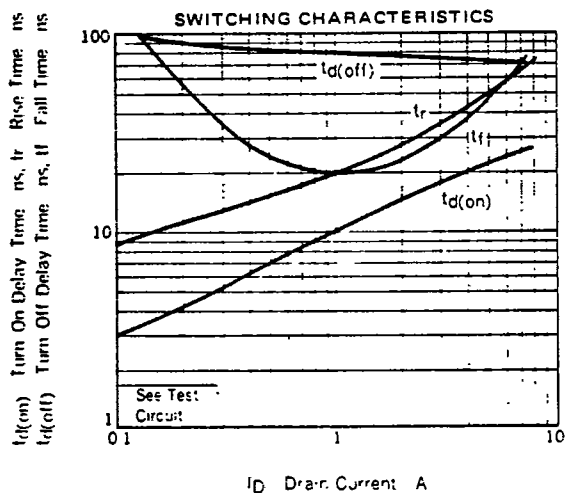
TYPICAL TRANSFER CHARACTERISTICS



GATE TO SOURCE CUTOFF VOLTAGE vs. CHANNEL TEMPERATURE



SWITCHING CHARACTERISTICS



SWITCHING TIME TEST CIRCUIT

